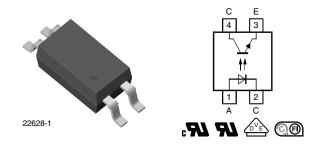
COMPLIANT



Vishay Semiconductors

Optocoupler, Phototransistor Output, Single Channel, Half Pitch Mini-Flat Package



FEATURES

- Low profile package (half pitch)
- AC isolation test voltage 3750 V_{RMS}
- · Low coupling capacitance of typical 0.3 pF
- · Current transfer ratio (CTR) selected into groups
- · Low temperature coefficient of CTR
- Wide ambient temperature range
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

LINKS TO ADDITIONAL RESOURCES



DESCRIPTION

The TCMT111X series consist of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 4 pin package.

APPLICATIONS

- Programmable logic controllers
- Modems
- · Answering machines
- · General applications

AGENCY APPROVALS

- UL 1577
- cUL
- DIN EN 60747-5-5 (VDE 0884-5)
- CQC
- BSI
- FIMKO

0	RDERING	G INFORM	MATION						
	Т	С	М	Т	1	1	1	#	SSOP-4
				PART N	UMBER				≥ 5 mm

AGENCY	CTR (%)							
CERTIFIED/PACKAGE	5 mA	10 mA		5 r	m A			
UL, cUL, BSI, VDE	50 to 600	100 to 200	100 to 300	80 to 160	130 to 260	200 to 400		
SSOP-4	TCMT1110	TCMT1113	TCMT1116	TCMT1117	TCMT1118	TCMT1119		

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
INPUT								
Reverse voltage		V_R	6	V				
Forward current		I _F	50	mA				
Forward surge current	t _P ≤ 10 μs	I _{FSM}	1.5	Α				
Power dissipation		P _{diss}	80	mW				
Junction temperature		Tj	125	°C				



ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT					
OUTPUT									
Collector emitter voltage		V _{CEO}	70	V					
Emitter collector voltage		V _{ECO}	7	V					
Collector current		I _C	50	mA					
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA					
Power dissipation		P _{diss}	150	mW					
Junction temperature		Tj	125	°C					
COUPLER									
Total power dissipation		P _{tot}	230	mW					
Operating ambient temperature range		T _{amb}	-40 to +110	°C					
Storage temperature range		T _{stg}	-40 to +125	°C					
Soldering temperature (1)		T _{sld}	260	°C					

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Wave soldering three cycles are allowed. Also refer to "Assembly Instructions" (www.vishay.com/doc?80054).

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT			
INPUT									
Forward voltage	I _F = 5 mA	V _F	-	1.08	1.4	V			
Junction capacitance	$V_R = 0$, $f = 1$ MHz	Cj	-	8	-	pF			
OUTPUT									
Collector emitter voltage	I _C = 100 μA	V _{CEO}	70	-	-	V			
Emitter collector voltage	I _E = 100 μA	V _{ECO}	7	-	-	V			
Collector dark current	$V_{CE} = 20 \text{ V}, I_F = 0$	I _{CEO}	-	-	100	nA			
COUPLER									
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 1 \text{ mA}$	V _{CEsat}	-	0.1	0.3	V			
Cut-off frequency	V_{CE} = 5 V, I_F = 10 mA, R_L = 100 Ω	f _c	-	100	-	kHz			
Coupling capacitance	f = 1 MHz	C _k	-	0.3	-	pF			

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
	$V_{CE} = 5 \text{ V}, I_{F} = 5 \text{ mA}$	TCMT1110	CTR	50	-	600	%
	$V_{CE} = 5 \text{ V}, \text{ I}_{F} = 10 \text{ mA} \\ \hline \\ V_{CE} = 5 \text{ V}, \text{ I}_{F} = 10 \text{ mA} \\ \hline \\ V_{CE} = 5 \text{ V}, \text{ I}_{F} = 5 \text{ mA} \\ \hline \\ \\ \hline \\ V_{CE} = 5 \text{ V}, \text{ I}_{F} = 5 \text{ mA} \\ \hline \\ \hline \\ \\ \hline \\ \\ \hline \\ \\ \hline \\ \\ \\ \\ \\ \\ $	TCMT1113	CTR	100	-	200	%
I _C /I _E		TCMT1114	CTR	160	-	320	%
IC/IF		TCMT1117	CTR	80	-	160	%
		%					
		TCMT1119	CTR	200	-	400	%



SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Delay time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega,$ (see figure 1)	t _d	-	4	-	μs	
Rise time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega,$ (see figure 1)	t _r	-	5.5	-	μs	
Fall time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega,$ (see figure 1)	t _f	-	7	-	μs	
Storage time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega,$ (see figure 1)	ts	-	1.5	-	μs	
Turn-on time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega,$ (see figure 1)	t _{on}	-	9.5	-	μs	
Turn-off time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega,$ (see figure 1)	t _{off}	-	8	-	μs	
Turn-on time	V_S = 5 V, I_F = 10 mA, R_L = 1 k Ω , (see figure 2)	t _{on}	-	3	-	μs	
Turn-off time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega,$ (see figure 2)	t _{off}	-	20	-	μs	

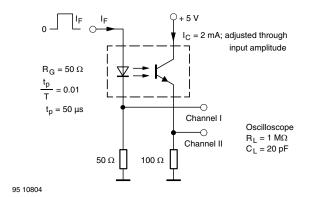


Fig. 1 - Test Circuit, Non-Saturated Operation

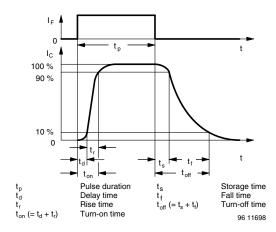


Fig. 3 - Switching Times

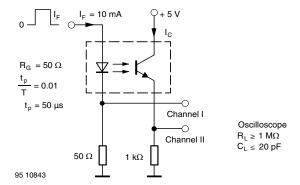


Fig. 2 - Test Circuit, Saturated Operation



SAFETY AND INSULATION RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Climatic classification (according to IEC 68 part 1)			55 / 110 / 21				
Comparative tracking index		CTI	175				
Maximum rated withstanding isolation voltage	40 % to 60 % RH, AC test of 1 min	V _{ISO}	3750	V _{RMS}			
Maximum transient isolation voltage		V _{IOTM}	6000	V			
Maximum repetitive peak isolation voltage		V _{IORM}	707	V			
Insulation resistance	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	10 ¹¹	Ω			
Isolation resistance (under fault conditions)	$V_{IO} = 500 \text{ V}, T_{amb} = T_{SI}$	R _{IO}	10 ⁹	Ω			
Output safety power		P _{SO}	350	mW			
Input safety current		I _{SI}	200	mA			
Input safety temperature		T _{SI}	175	°C			
Apparent charge test voltage (method A)	V_{IORM} x 1.6 = V_{PR} , type and sample test t_m = 60 s, partial discharge < 5 pC	V_{PR}	1132	V_{peak}			
Apparent charge test voltage (method B)	V_{IORM} x 1.875 = V_{PR} , 100 % production test with t_m = 1 s, partial discharge < 5 pC	V_{PR}	1326	V _{peak}			
Creepage distance			≥ 5	mm			
Clearance distance			≥ 5	mm			
Insulation thickness		DTI	≥ 0.4	mm			
Environment (pollution degree in accordance to DI	N VDE 0109)		2				

Note

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

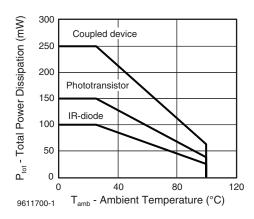


Fig. 4 - Total Power Dissipation vs. Ambient Temperature

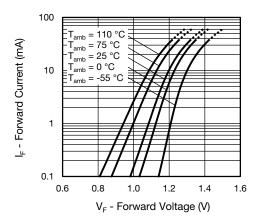


Fig. 5 - Forward Voltage vs. Forward Current

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.

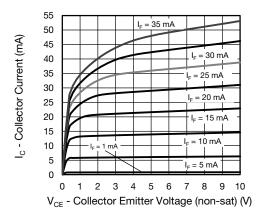


Fig. 6 - Collector Current vs. Collector Emitter Voltage

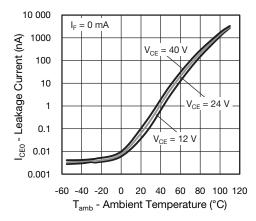


Fig. 7 - Leakage Current vs. Ambient Temperature

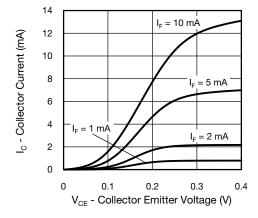


Fig. 8 - Collector Current vs. Collector Emitter Voltage

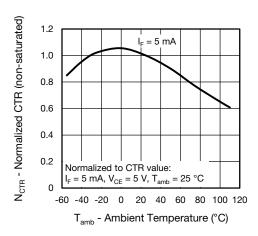


Fig. 9 - Normalized Current Transfer Ratio (non-saturated) vs.

Ambient Temperature

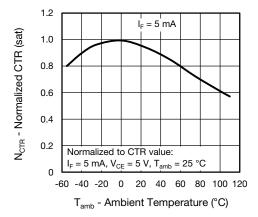


Fig. 10 - Normalized Current Transfer Ratio (saturated) vs.
Ambient Temperature

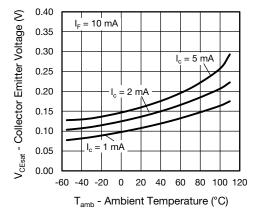


Fig. 11 - Collector Emitter Voltage vs. Ambient Temperature

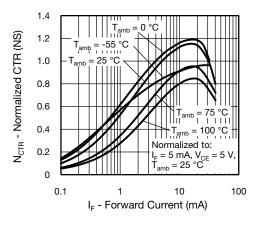


Fig. 12 - Normalized CTR (non-saturated) vs. Forward Current

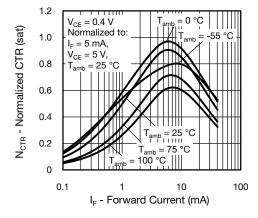


Fig. 13 - Normalized CTR (saturated) vs. Forward Current

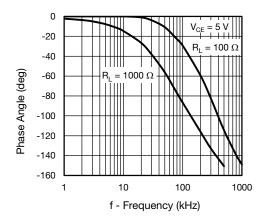


Fig. 14 - F_{CTR} vs. Phase Angle

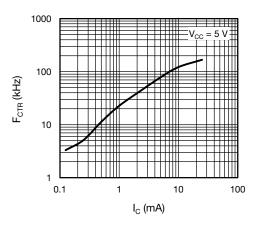


Fig. 15 - F_{CTR} vs. Collector Current

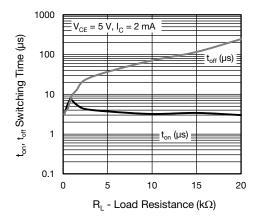
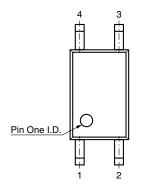
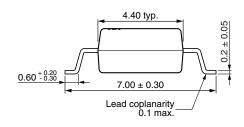


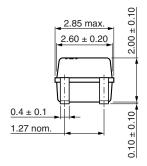
Fig. 16 - Switching Time vs. Load Resistance

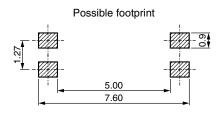


PACKAGE DIMENSIONS in millimeters

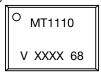








PACKAGE MARKING (example of TCMT1110)



Note

• XXXX = LMC (lot marking code)

PACKAGING INFORMATION (TAPE AND REEL) in millimeters

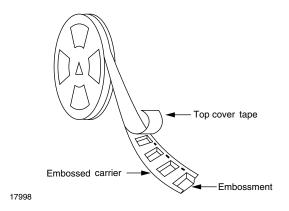


Fig. 17 - Tape and Reel Shipping Medium

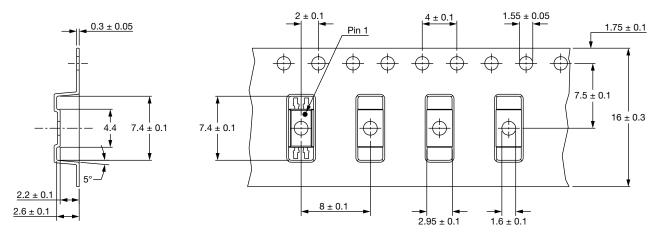


Fig. 18 - Tape and Reel Packing (3000 parts per reel)

SOLDER PROFILES

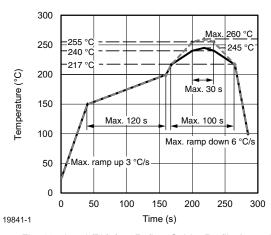


Fig. 19 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020 for SMD Devices

HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited

Conditions: T_{amb} < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020



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